

New Product

Vishay Siliconix

N-Channel 75-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{(BR)DSS} (V)	$r_{DS(on)}(\Omega)$	I _D (A)			
75	0.010 at V _{GS} = 10 V	110			

FEATURES

- TrenchFET[®] Power MOSFET
- · New Low Thermal Resistance Package



APPLICATIONS

- Automotive
 - Boardnet 42-VEP and ABS
 - Motor Drives
- High Current
- DC/DC Converters



Ordering Information: SUM110N08-10 SUM110N08-10-E3 (Lead (Pb)-free)

N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_A = 25$ °C, unless otherwise noted				
Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	75	V
Gate-Source Voltage		V _{GS}	± 20	v
Continuous Drain Current (T _J = 175 °C)	T _C = 25 °C		110	
	T _C = 125 °C	I _D	63 ^a	A
Pulsed Drain Current		I _{DM}	350	^
Avalanche Current		I _{AR}	75	
Repetitive Avalanche Energy ^a	L = 0.1 mH	E _{AR}	280	mJ
	$T_C = 25 ^{\circ}C$ $T_A = 25 ^{\circ}C^c$	В	200 ^b	W
Maximum Power Dissipation ^a	T _A = 25 °C ^c	P _D	3.7	VV
Operating Junction and Storage Temperature Range		Tu, Teta	- 55 to 175	°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Limit	Unit	
Maximum Junction-to-Ambient	PCB Mount ^c	R_{thJA}	40	°C/W	
Maximum Junction-to-Case		R _{thJC}	0.75	J 6/VV	

Notes:

- a. Duty cycle \leq 1 %.
- b. See SOA curve for voltage derating.
- c. When mounted on 1" square PCB (FR-4 material).

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^{*} Pb containing terminations are not RoHS compliant, exemptions may apply

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SPECIFICATIONS T _J = 25 °C			BA:	T	NA	1114	
Parameter	Symbol	Test Condition	Min	Тур	Max	Unit	
Static			ı		T T		
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{DS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	75			V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu\text{A}$	2.5		4.0	•	
Gate Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = 75 \text{ V}, V_{GS} = 0 \text{ V}$			1		
	I _{DSS}	$V_{DS} = 75 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$	_{SS} = 0 V, T _J = 125 °C		50	μΑ	
		$V_{DS} = 75 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 175 ^{\circ}\text{C}$			250		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	120			Α	
Drain-Source On-State Resistance ^a		$V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$		0.0055	0.010	5 Ω	
	r _{DS(on)}	$V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}, T_J = 125 ^{\circ}\text{C}$			0.0185		
		$V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}, T_J = 175 ^{\circ}\text{C}$			0.0245		
Forward Transconductance	9 _{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 30 \text{ A}$	30			S	
Dynamic ^b							
Input Capacitance	C _{iss}			5250		pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$		700			
Reverse Transfer Capacitance	C _{rss}			310			
Total Gate Charge ^c	Q _q			90	165	nC	
Gate-Source Charge ^c	Q _{qs}	$V_{DS} = 35 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 110 \text{ A}$		24			
Gate-Drain Charge ^c	Q _{gd}			27			
Turn-On Delay Time ^c	t _{d(on)}			20	30		
Rise Time ^c	t _r	$V_{DD} = 35 \text{ V}, R_1 = 0.4 \Omega$		100	150	ns	
Turn-Off DelayTime ^c	t _{d(off)}	$I_D \cong 110 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 2.5 \Omega$		45	70		
Fall Time ^c	t _f			75	115		
Source-Drain Diode Ratings and Char	racteristics (T _C	= 25 °C) ^b	I.		l L		
Continous Current	I _S				110		
Pulsed Current	I _{SM}				350	Α	
Forward Voltage ^a	V _{SD}	I _F = 110 A, V _{GS} = 0 V		1.0	1.5	V	
Reverse Recovery Time	t _{rr}			75	120	ns	
Peak Reverse Recovery Current	I _{RM(REC)}	I _F = 85 A, di/dt = 100 A/μs		3.5	7	Α	
Reverse Recovery Charge	Q _{rr}			0.13	0.30	μC	

Notes:

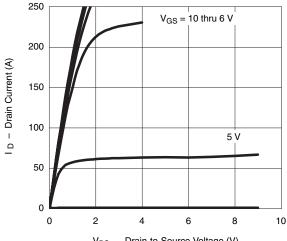
- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



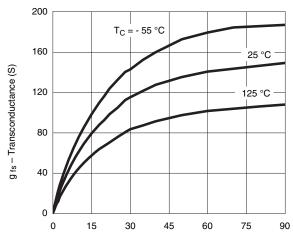
New Product

TYPICAL CHARACTERISTICS $T_A = 25$ °C, unless otherwise noted

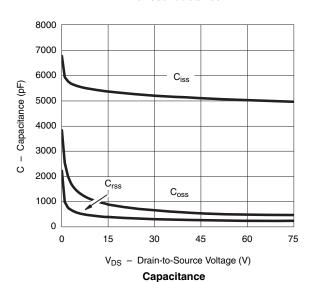


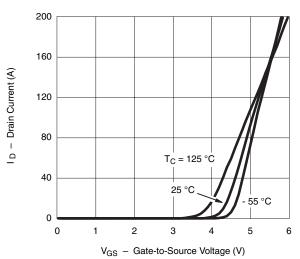
V_{DS} - Drain-to-Source Voltage (V)

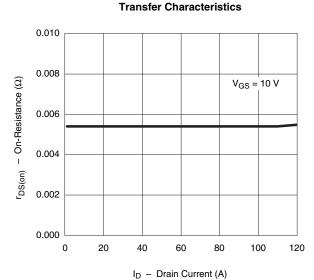
Output Characteristics



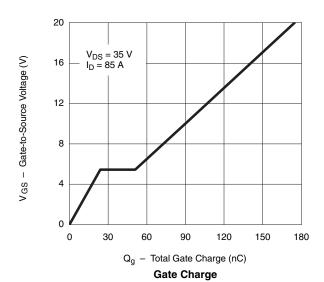
I_D - Drain Current (A) **Transconductance**







On-Resistance vs. Drain Current



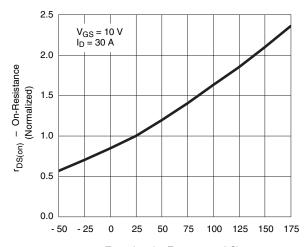
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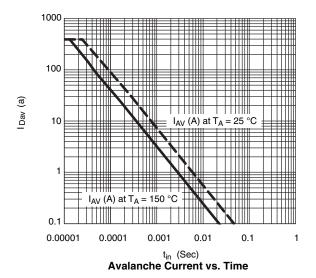
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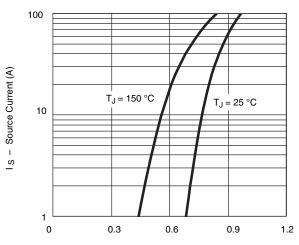


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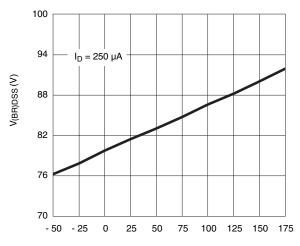


 T_J – Junction Temperature (°C) On-Resistance vs. Junction Temperature





V_{SD} - Source-to-Drain Voltage (V)
Source-Drain Diode Forward Voltage



T_J - Junction Temperature (°C)

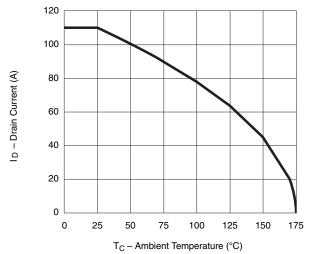
Drain Source Breakdown vs.

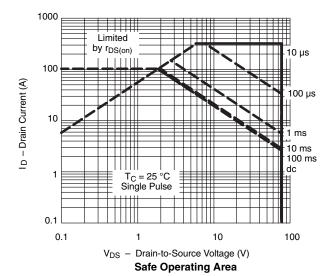
Junction Temperature

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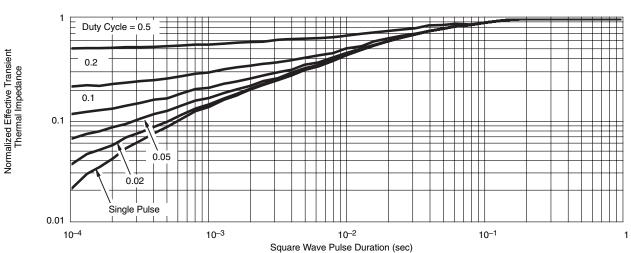
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Maximum Avalanche and Drain Current vs. Case Temperature



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?71838.

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